BU508AW

GENERAL DESCRIPTION

High voltage, high-speed switching npn transistors in a plastic envelope, primarily for use in horizontal deflection circuits of colour television receivers.

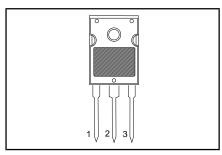
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 \text{ V}$	-	1500	V
V _{CEO}	Collector-emitter voltage (open base)		-	700	V
Ic	Collector current (DC)		-	8	Α
1 1	Collector current peak value		-	15	Α
P _{tot}	Total power dissipation	$T_{mb} \le 25 ^{\circ}C$	-	125	W
P _{tot} V _{CEsat}	Collector-emitter saturation voltage	$ T_{mb} \le 25 ^{\circ}C$ $ I_{C} = 4.5 A; I_{B} = 1.6 A$	-	1.0	V
I _{Csat}	Collector saturation current	f = 16 kHz	4.5	-	Α
t _f	Fall time	$I_{Csat} = 4.5 \text{ A}; f = 16 \text{kHz}$	0.7	-	μs

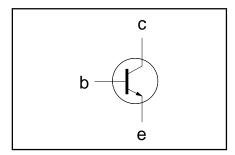
PINNING - SOT429

PIN	DESCRIPTION	
1	base	
2	collector	
3	emitter	
tab	collector	

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 \text{ V}$	-	1500	V
V_{CEO}	Collector-emitter voltage (open base)		-	700	V
I _C	Collector current (DC)		-	8	Α
I I _{CM}	Collector current peak value		-	15	Α
I IB	Base current (DC)		-	4	Α
I _{BM}	Base current peak value		-	6	Α
P _{tot}	Total power dissipation	$T_{mb} \leq 25 ^{\circ}C$	-	125	W
T _{stq}	Storage temperature	IIID	-65	150	°C
T _j	Junction temperature		-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-mb}	Junction to mounting base	-	-	1.0	K/W
R _{th j-a}	Junction to ambient	in free air	45	-	K/W

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STATIC CHARACTERISTICS

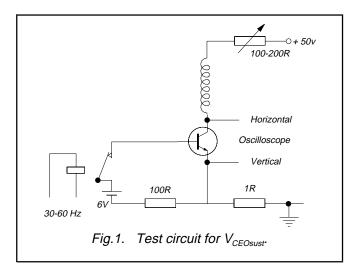
 $T_{mb} = 25$ °C unless otherwise specified

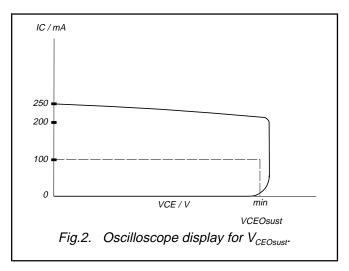
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES}	Collector cut-off current 1	$egin{aligned} V_{BE} &= 0 \ V; \ V_{CE} &= V_{CESMmax} \ V_{BE} &= 0 \ V; \ V_{CE} &= V_{CESMmax}; \end{aligned}$	-	-	1.0	mA
I _{CES}		$V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax};$ $T_i = 125 \text{ °C}$	-	-	2.0	mA
I _{EBO}	Emitter cut-off current	$V_{ER} = 6.0 \text{ V}$: $I_{C} = 0 \text{ A}$	-	-	10	mΑ
V _{CEOsus}	Collector-emitter sustaining voltage	I _B = 0 A; I _C = 100 mA; L = 25 mH	700	-	-	V
V_{CEsat}	Collector-emitter saturation voltages	$I_{\rm C} = 4.5 \text{A}; I_{\rm B} = 1.6 \text{A}$	-	-	1.0	V
V _{BEsat}	Base-emitter saturation voltage	$I_{\rm C} = 4.5 \text{ A}; I_{\rm B} = 2.0 \text{ A}$	-	-	1.1	V
h _{FE}	DC current gain	$I_{C} = 100 \text{ mA}; V_{CE} = 5 \text{ V}$	6	13	30	-

DYNAMIC CHARACTERISTICS

 T_{mb} = 25 °C unless otherwise specified

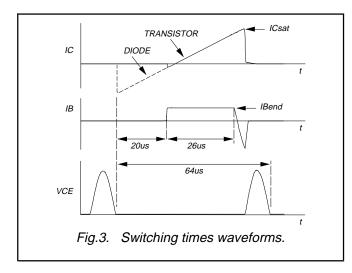
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
f⊤	Transition frequency at f = 5 MHz	$I_C = 0.1 \text{ A; } V_{CE} = 5 \text{ V}$	7	-	MHz
C _c	Collector capacitance at f = 1MHz	V _{CB} = 10 V	125	-	рF
t _s	Switching times (16 kHz line deflection circuit) Turn-off storage time Turn-off fall time	$ \begin{vmatrix} I_{Csat} = 4.5 \text{ A;} L_c = 1 \text{ mH;} C_{fb} = 4 \text{ nF} \\ I_{B(end)} = 1.4 \text{ A;} L_B = 6 \mu\text{H;} \text{ -V}_{BB} = \text{-4 V;} \\ \end{vmatrix} $	6.5 0.7		μs μs

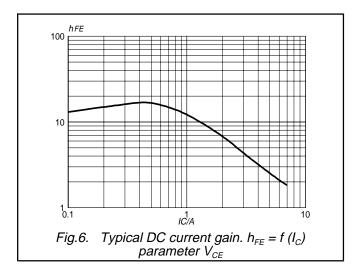


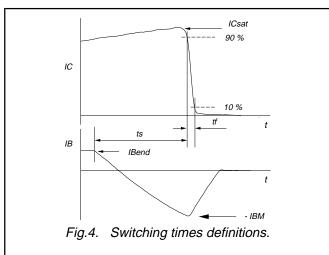


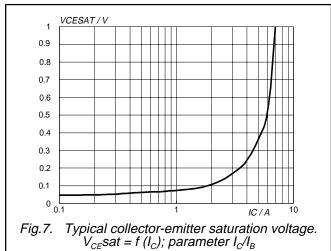
¹ Measured with half sine-wave voltage (curve tracer).

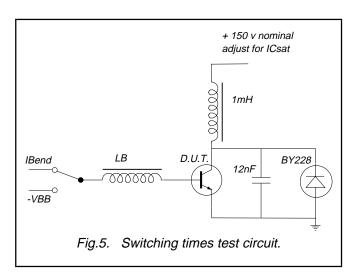
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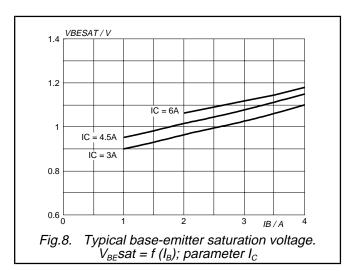












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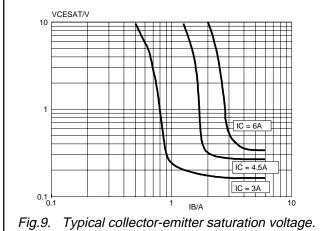
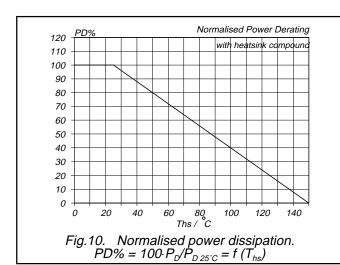


Fig.9. Typical collector-emitter saturation voltage. V_{CE} sat = $f(I_B)$; parameter I_C



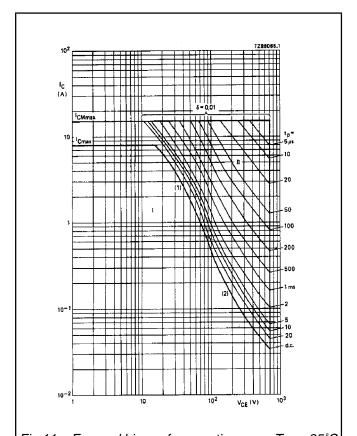


Fig.11. Forward bias safe operating area. $T_{mb} < 25^{\circ}C$ (1) $P_{tot \, max}$ line. (2) Second-breakdown limit (independent of

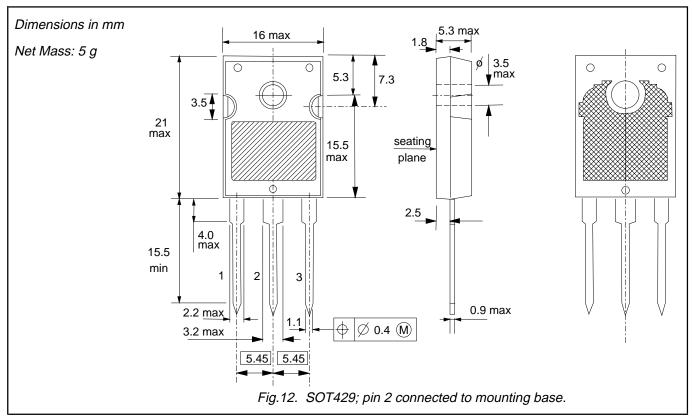
- temperature).

 I Region of permissible DC operation.

 II Permissible extension for repetitive operation.

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MECHANICAL DATA



Notes

- Refer to mounting instructions for SOT429 envelope.
 Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limitin or conferen				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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